# VISHAY

## 1N746A to 1N759A

#### **Vishay Semiconductors**

#### **Zener Diodes**

#### **Features**

- Silicon Planar Power Zener Diodes.
- Standard Zener voltage tolerance is ± 5 % for "A" suffix.

# 94 9367

#### **Mechanical Data**

Case: DO-35 Glass Case Weight: approx. 130 mg

#### Packaging codes/options:

TR / 10k per 13 " reel, 30k/box
TAP / 10k per Ammo tape (52 mm tape), 30k/box

#### **Absolute Maximum Ratings**

T<sub>amb</sub> = 25 °C, unless otherwise specified

	4.11.2					
Parameter		Test condition	Symbol	Value	Unit	
	Zenner current (see Table "Characteristics")	a sub- Co		W.073		
	Power dissipation	T <sub>amb</sub> = 75 °C	P <sub>tot</sub>	500 <sup>1)</sup>	W	

 $<sup>^{1)}</sup>$  T<sub>L</sub> is measured that leads at a distance of 3/8 " from case are kept at ambient temperature

#### **Maximum Thermal Resistance**

T<sub>amb</sub> = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Thermal resistance junction to ambient air		$R_{ hetaJA}$	300 <sup>1)</sup>	°C/W
Maximum junction temperature		T <sub>j</sub>	175	°C
Storage temperature range		T <sub>S</sub>	- 65 to + 175	°C

<sup>1)</sup> Valid provided that leads at a distance of 3/8 " from case are kept at ambient temperature



## 1N746A to 1N759A

#### **Vishay Semiconductors**



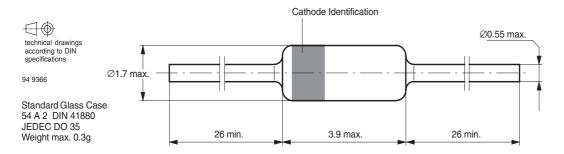
#### **Electrical Characteristics**

1N746A to 1N759A

Partnumber	Nominal Zener Voltage	Test Current	Maximum Dynamic Impedance	Maximum Regulator Current	Maximum Reverse Leakage Current (I <sub>R</sub> @ V <sub>R</sub> = 1V)	
	V <sub>Z</sub> @ I <sub>ZT</sub> <sup>3)</sup>	I <sub>ZT</sub>	Z <sub>ZT</sub> @ I <sub>ZT</sub> <sup>1)</sup>	I <sub>ZM</sub> <sup>2)</sup>	T <sub>amb</sub> = 25 °C	T <sub>amb</sub> = 150 °C
	V	mA	Ω	mA	μΑ	μΑ
1N746A	3.3	20	28	110	10	30
1N747A	3.6	20	24	100	10	30
1N748A	3.9	20	23	95	10	30
1N749A	4.3	20	22	85	2	30
1N750A	4.7	20	19	75	2	30
1N751A	5.1	20	17	70	1	20
1N752A	5.6	20	11	65	1	20
1N753A	6.2	20	7	60	0.1	20
1N754A	6.8	20	5	55	0.1	20
1N755A	7.5	20	6	50	0.1	20
1N756A	8.2	20	8	45	0.1	20
1N757A	9.1	20	10	40	0.1	20
1N758A	10	20	17	35	0.1	20
1N759A	12	20	30	30	0.1	20

<sup>1)</sup>The Zener impedance is derived from the 1 kHz AC voltage which results when an AC current having an RMS value equal to 10 % of the Zener current  $(I_{ZT})$  is superimposed on  $I_{ZT}$ . Zener impedance is measured at two points to insure a sharp knee on the breakdown curve and to eliminate unstable units.

#### Package Dimensions in mm



2 Rev. 2, 04-Apr-03

<sup>&</sup>lt;sup>2)</sup>Valid provided that leads at a distance of 3/8 " from case are kept at ambient temperature.

<sup>&</sup>lt;sup>3)</sup>Measured with device junction in thermal equilibrium.

#### 1N746A to 1N759A



#### **Vishay Semiconductors**

#### **Ozone Depleting Substances Policy Statement**

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

**Vishay Semiconductor GmbH** has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

**Vishay Semiconductor GmbH** can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

# We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany Telephone: 49 (0)7131 67 2831, Fax number: 49 (0)7131 67 2423

Document Number 85756 www.vishay.com